

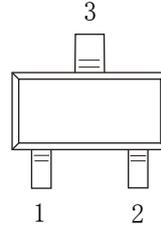
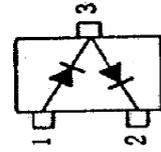


1SS362 Switching Diodes

■ Features

- Fast Switching Speed
- Low Forward Voltage
- Fast Reverse Recovery Time
- Small Total Capacitance

Marking C3



SOT-523

■ Absolute Maximum Ratings Ta = 25°C

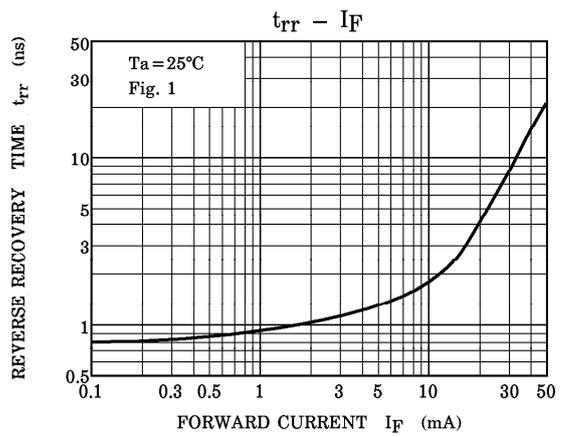
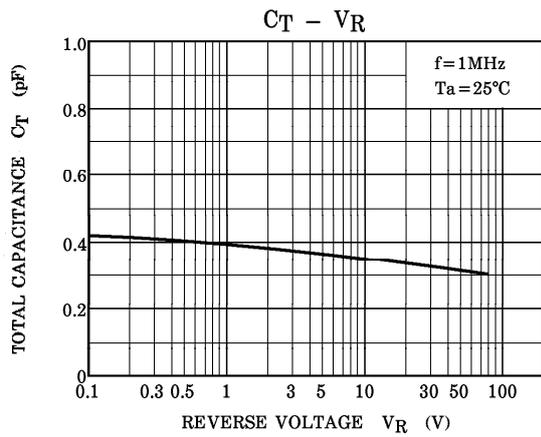
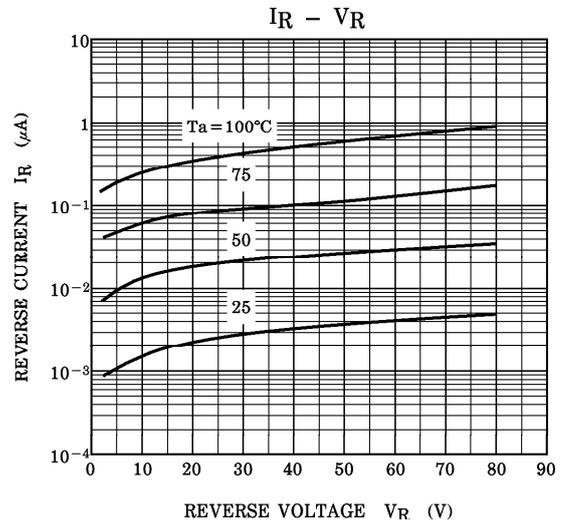
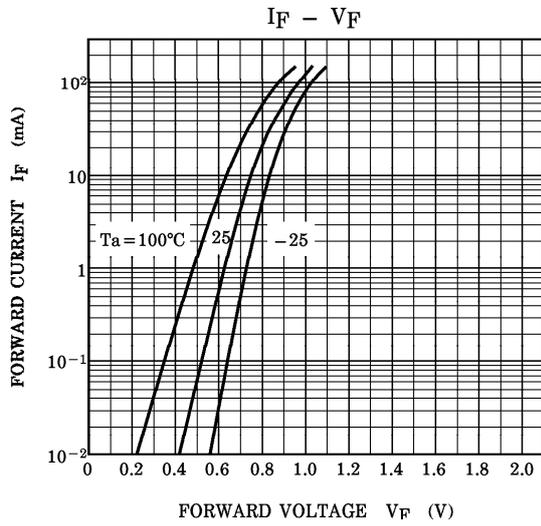
Parameter	Symbol	Rating	Unit
Peak Reverse Voltage	V _{RM}	85	V
Reverse Voltage	V _R	80	
Average Rectified Output Current	I _O	80	mA
Forward Continuous Current	I _{FM}	240	
Peak Forward Surge Current @ t=10ms	I _{FSM}	1	A
Power Dissipation	P _d	100	mW
Junction Temperature	T _J	125	°C
Storage Temperature range	T _{stg}	-55 to 125	

■ Electrical Characteristics Ta = 25°C

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Reverse breakdown voltage	V _R	I _R = 100uA	80			V
Forward voltage	V _{F1}	I _F = 1mA		0.63		
	V _{F2}	I _F = 10 mA		0.75		
	V _{F3}	I _F = 100 mA			1.2	
Reverse voltage leakage current	I _{R1}	V _R = 30 V			0.1	uA
	I _{R2}	V _R = 80 V			0.5	
Junction capacitance	C _j	V _R = 0 V, f= 1 MHz			3	pF
Reverse recovery time	t _{rr}	I _F =10mA			4	ns

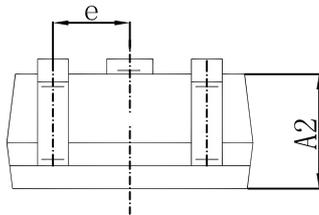
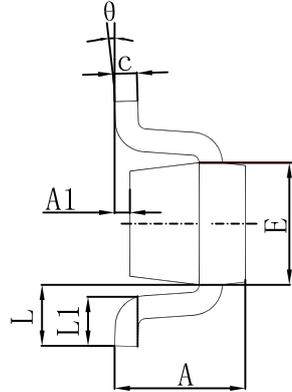
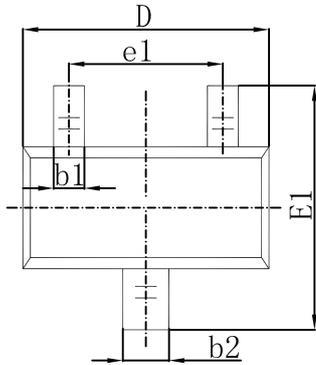


Typical Characteristics



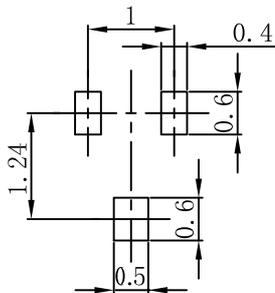


SOT-523 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.700	0.900	0.028	0.035
A1	0.000	0.100	0.000	0.004
A2	0.700	0.800	0.028	0.031
b1	0.150	0.250	0.006	0.010
b2	0.250	0.350	0.010	0.014
c	0.100	0.200	0.004	0.008
D	1.500	1.700	0.059	0.067
E	0.700	0.900	0.028	0.035
E1	1.450	1.750	0.057	0.069
e	0.500 TYP.		0.020 TYP.	
e1	0.900	1.100	0.035	0.043
L	0.400 REF.		0.016 REF.	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°

SOT-523 Suggested Pad Layout



- Note:
1. Controlling dimension: in millimeters.
 2. General tolerance: $\pm 0.05\text{mm}$.
 3. The pad layout is for reference purposes only.